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# Efficient photocatalytic oxidation of methane over $\beta$ -Ga<sub>2</sub>O<sub>3</sub>/activated carbon composites†

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Efficient oxidation of methane over heterogeneous catalysts under ambient conditions is still a challengeable study toward C1 utilization and atmospheric cleansing. In this study, by using a hydrolysis method combined with an impregnation process,  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> nanoparticles supported uniformly on activated carbon (AC) can be obtained readily. The as-prepared Ga<sub>2</sub>O<sub>3</sub>/AC composites show efficient performance for photocatalytic oxidation of CH<sub>4</sub> under ultraviolet irradiation. The experimental results indicate that photocatalytic activity toward CH<sub>4</sub> oxidation is strongly dependent on the weight ratio of Ga<sub>2</sub>O<sub>3</sub> to AC. 15%-Ga<sub>2</sub>O<sub>3</sub>/AC exhibits the highest catalytic activity, which is more than sixfold of P25, a benchmark photocatalyst. The photoluminescence spectra show the decreased recombination centers and the diminished recombination of photo-generated electrons (e<sup>-</sup>) and holes (h<sup>+</sup>) when Ga<sub>2</sub>O<sub>3</sub> nanoparticles were deposited on AC. Further investigation reveals that the excellent photo-oxidation activity for CH<sub>4</sub> over Ga<sub>2</sub>O<sub>3</sub>/AC can be ascribed to a synergistic effect involving strong adsorption capacity and improved separation of photo-generated e<sup>-</sup>/h<sup>+</sup> pairs. Moreover, the photocatalytic oxidation of CH<sub>4</sub> obeys pseudo-first-order kinetics and the cycling experiment indicates that Ga<sub>2</sub>O<sub>3</sub>/AC composites possess stable photocatalytic performance for CH<sub>4</sub> oxidation. The underlying photo-oxidation mechanism is also investigated using electron paramagnetic resonance (ESR) and radical scavenging experiments. This study demonstrates that photocatalysis with Ga<sub>2</sub>O<sub>3</sub>/AC is a highly efficient method toward the oxidation of low concentrations of CH<sub>4</sub>, which provides valuable information for atmospheric environmental cleansing.

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## 1. Introduction

As the major ingredient of natural gas, CH<sub>4</sub> is widely employed as a clean fuel and is also a common carbon source for chemical production. In view of its effect on improving the living quality of human beings, the discharge of CH<sub>4</sub> has been considered to be negligible for a long time, which results in an ever-increasing CH<sub>4</sub> concentration in the atmosphere.<sup>1,2</sup> Recently, with the increasing concern surrounding atmospheric contamination and global warming, the negative effects of CH<sub>4</sub> emission receive more and more attention.<sup>3,4</sup> According to a report of the

Intergovernmental Panel on Climate Change, CH<sub>4</sub> is responsible for about twenty percent of man-made global warming and the greenhouse gas effect of CH<sub>4</sub> is nearly 28 times greater than that of an equivalent mass of CO<sub>2</sub>.<sup>5</sup> More seriously, coal-bed gas or shale gas exploitation results in the increase of CH<sub>4</sub> release into the atmosphere. Therefore, the conversion of atmospheric methane into equimolar amounts of carbon dioxide is extremely important for retarding global warming.

Due to the high energy of C–H bond (434 kJ mol<sup>-1</sup>) and nonpolar characteristics of CH<sub>4</sub> molecule, oxidation of CH<sub>4</sub> has been mainly studied *via* thermal catalysis with noble metal and transition-metal oxide catalysts in the past decades.<sup>6,7</sup> However, the high reaction temperature (~673 K) and inefficiency in oxidizing low concentration of CH<sub>4</sub> are the defects of conventional thermo-catalysis. Although the microorganism treatments using methane oxidative bacteria could decompose CH<sub>4</sub>,<sup>8,9</sup> it has been proved to be inefficient for the practical application because this approach is time consuming and difficult to control. Wei and his co-workers have recently reported the oxidation of CH<sub>4</sub> with hydroxyl radicals (<sup>•</sup>OH) generated *via* Fenton reagent.<sup>10</sup> The results demonstrate that <sup>•</sup>OH derived from Fenton reagent can drive the oxidation of CH<sub>4</sub> under a certain reaction condition. However, the homogeneous Fenton systems have some limitations because Fe<sup>2+</sup> and H<sub>2</sub>O<sub>2</sub>

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† Electronic supplementary information (ESI) available: The schematic diagram of photocatalytic experimental apparatus; SEM image of bare Ga<sub>2</sub>O<sub>3</sub> nanoparticles; the effect of light intensity on the photocatalytic oxidation of CH<sub>4</sub>; XRD pattern and SEM image of as-prepared 15%-TiO<sub>2</sub>/AC composite; the amount of produced CO<sub>2</sub> during the photocatalytic oxidation of CH<sub>4</sub>; the comparison of XRD patterns and XPS spectra between freshly prepared and recycled 15%-Ga<sub>2</sub>O<sub>3</sub>/AC photocatalyst. See DOI: 10.1039/c7ra05692c



cannot be separated from the reaction system and reused for the next cycle. Additionally, iron ions are easy to precipitate under an alkaline condition, which restricts the  $\text{CH}_4$  removal with Fenton reagent can be only performed in a narrow pH range.

Heterogeneous photocatalysis is regarded as an ideal technology for solving the urgent energy and environmental issues,<sup>11–13</sup> especially in removing various gaseous pollutants at ambient pressure and temperature.<sup>14,15</sup> Previous studies have also indicated  $\text{CH}_4$  molecules can be activated and subsequently oxidized *via*  $\text{TiO}_2$  photocatalytic technology,<sup>16,17</sup> however, the efficiency of  $\text{CH}_4$  photo-oxidation remains notoriously low. Adsorption and photoreaction are two successively key steps, which are generally interactional during the heterogeneous photocatalytic process. Surface adsorption and the diffusion of reactants to active sites are the preconditions of photocatalytic reactions. Strong adsorption of target reactants facilitates the catalytic reaction between the adsorbed reactant and surface active species. As a result, the efforts toward improving the adsorption of reactants in photocatalytic system have been made through constructing porous materials<sup>18,19</sup> or adsorbent-loaded composites.<sup>20,21</sup> Fabricating of the composites with adsorptive support and traditional photocatalyst is considered as an effective approach to obtain the adsorption-enhanced photocatalyst. Adsorbent-loaded photocatalysts usually possess excellent synergistic effect because of the continuous transfer of adsorbed reactants to the supported photocatalytic active sites. Meanwhile, the prolonged retention-time of intermediates on the composite catalyst facilitates improving the mineralization of pollutants.

Carbon materials, such as graphene oxides (GO),<sup>22</sup> carbon nanotube (CNT)<sup>23,24</sup> and activated carbon (AC),<sup>25</sup> have been extensively used as one kind of excellent supports for semiconductor-based photocatalyst nanoparticles, which can efficiently improve the distribution of active components, the electron-transfer from semiconductor particles to carbon supports, and the stability of catalysts. Furthermore, in the field of  $\text{CH}_4$  adsorption and storage, porous carbon materials have also received wide attention due to their outstanding adsorption capacity.<sup>26,27</sup> Among these carbon-based supports, AC is commonly used owing to its unique advantages, including abundant microporous structure, high adsorption capacity, low production cost, and facile recycling.

$\beta$ -Gallium oxide ( $\beta\text{-Ga}_2\text{O}_3$ ) has wider band-gap energy (4.8 eV) than classic photocatalyst  $\text{TiO}_2$  (3.2 eV). The reported valence-band potential (−7.75 eV) of  $\text{Ga}_2\text{O}_3$  is lower than that (−7.41 eV) of  $\text{TiO}_2$  (relative to the vacuum energy level) and the conduction-band potential (−2.95 eV) of  $\text{Ga}_2\text{O}_3$  is higher than that (−4.21 eV) of  $\text{TiO}_2$ .<sup>28,29</sup> In consequence, the photo-holes and photo-electrons generated upon the surface of  $\text{Ga}_2\text{O}_3$  possess stronger redox capacity than those formed over  $\text{TiO}_2$ . This contributes to the oxidation of persistent organic pollutants and the mineralization of stable intermediates upon the surface of  $\text{Ga}_2\text{O}_3$ .<sup>29</sup> In addition,  $\text{Ga}_2\text{O}_3$  is also an environmental friendly material according to Worksafe Australia criteria. Fu and his colleagues have reported the photocatalytic degradation of volatile organic contaminants (e.g. benzene and

methylbenzene) over  $\beta\text{-Ga}_2\text{O}_3$  nanoparticles under ambient conditions and found that the photocatalytic activity of  $\beta\text{-Ga}_2\text{O}_3$  particles was much superior to commercial P25.<sup>28,29</sup> Porous  $\beta\text{-Ga}_2\text{O}_3$  was highly photoactive for mineralizing benzene to  $\text{CO}_2$  and no obvious deactivation was observed during the prolonged irradiation about 80 h.<sup>28</sup> The high activity and long-term stability of  $\text{Ga}_2\text{O}_3$  could be primarily ascribed to its wider band gap energy and the resulting stronger oxidative capacity.

In this study, activated carbon (AC) supported  $\beta\text{-Ga}_2\text{O}_3$  composites ( $\text{Ga}_2\text{O}_3/\text{AC}$ ) were prepared *via* an *in situ* synthetic method, including facile hydrolysis and impregnation process. The structure and physical–chemical properties of as-prepared  $\text{Ga}_2\text{O}_3/\text{AC}$  were characterized by using various analysis techniques.  $\text{Ga}_2\text{O}_3/\text{AC}$  composites demonstrate excellent photocatalytic activity for methane oxidation under ultraviolet irradiation.  $\beta\text{-Ga}_2\text{O}_3$  is chosen because it is an environmental friendly semiconductor with wide band-gap satisfying the requirement of strong oxidation capability. AC facilitates the adsorption of  $\text{CH}_4$  molecules and the uniform distribution of  $\text{Ga}_2\text{O}_3$  nanoparticles. The effects of  $\text{Ga}_2\text{O}_3$  weight ratios, irradiation intensity, and initial  $\text{CH}_4$  concentration on the photocatalytic oxidation efficiency were studied systematically. The results of dark-adsorption experiments and PL spectra indicate that the superior photocatalytic activity of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites can be ascribed to a synergistic effect involving strong adsorption capacity and improved separation of photo-generated  $\text{e}^-/\text{h}^+$  pairs. Besides, the photocatalytic oxidation of  $\text{CH}_4$  over  $\text{Ga}_2\text{O}_3/\text{AC}$  obeys pseudo-first-order kinetics. The underlying photo-oxidation mechanism is also investigated using electron paramagnetic resonance (ESR) and radicals scavenging experiments. The present work provides theoretical support and green approach to  $\text{CH}_4$  oxidation and atmospheric environmental cleansing.

## 2. Experimental section

### 2.1 Materials and agents

Gallium nitrate hydrate was purchased from Strem Chemicals. Anhydrous ethanol, tetrabutyl orthotitanate, acetic acid and ammonia solution were obtained from Aladdin Industrial Inc. (Shanghai, P.R. China). The standard gas of  $\text{N}_2$ ,  $\text{CH}_4$  and  $\text{O}_2$  (purity > 99.99%) were obtained from Jinggao Gas Inc. (Beijing, P.R. China). All chemicals from commercial sources were used without further purification except AC (AP4-60, purchased by Suzhou Calgon Carbon Inc.).

### 2.2 Preparation of photocatalyst

The commercial AC was firstly grinded and filtrated using a 60 mesh filter. The obtained AC particles were treated successively with 10% NaOH solution and 10%  $\text{HNO}_3$  solution. The products were collected, washed with deionized (DI) water several times and dried at 70 °C.

$\text{Ga}_2\text{O}_3/\text{AC}$  composite photocatalysts were fabricated using hydrolysis method combined with impregnation process. In a typical synthesis, 2 g of treated AC was dispersed into 30 mL DI water, followed by vigorous stirring 30 min to obtain



a uniform suspension. 1.0 g of gallium nitrate hydrate was dissolved in 20 mL of anhydrous ethanol to form a homogenous solution, which was added dropwise into the above suspension under magnetic stir. After 1 h, the mixed solution of ethanol and ammonia solution (volume ratio 1 : 1) was added slowly into the obtained suspension, which kept continuous stirring for 3 h at room temperature.<sup>28</sup> The resulting precipitate was centrifuged, washed with DI water, dried at 80 °C and calcinated at 600 °C for 2 h to prepare Ga<sub>2</sub>O<sub>3</sub>/AC. For simplicity, it is assumed that all of gallium nitrate hydrate was converted to Ga<sub>2</sub>O<sub>3</sub>. By changing the amount of gallium nitrate, Ga<sub>2</sub>O<sub>3</sub>/AC composites with different weight ratios of Ga<sub>2</sub>O<sub>3</sub> were obtained and labeled as *x*-Ga<sub>2</sub>O<sub>3</sub>/AC, which *x* represents the weight ratio of Ga<sub>2</sub>O<sub>3</sub> in the as-prepared composites. According to the above-mentioned way, a series of Ga<sub>2</sub>O<sub>3</sub>/AC composites with Ga<sub>2</sub>O<sub>3</sub> weight ratio of 5%, 10%, 15%, 20% and 25% were prepared and denoted as 5%-Ga<sub>2</sub>O<sub>3</sub>/AC, 10%-Ga<sub>2</sub>O<sub>3</sub>/AC, 15%-Ga<sub>2</sub>O<sub>3</sub>/AC, 20%-Ga<sub>2</sub>O<sub>3</sub>/AC and 25%-Ga<sub>2</sub>O<sub>3</sub>/AC, respectively.

For comparison, TiO<sub>2</sub>/AC nanocomposite sample was also synthesized *via in situ* compositing process according to the recent report.<sup>30</sup> Briefly, a certain amount of treated AC was dispersed into 30 mL DI water, which was stirred for 30 min to ensure the thorough dispersion of AC. Then, 2 mL of tetrabutyl titanate (TBOT) was mixed with 10 mL anhydrous alcohol and added dropwise to the above suspension of AC with magnetic stirring. After stirring for 3 h, the suspension was treated under microwave irradiation at 700 W for 15 min. The precipitates thus obtained were centrifuged, washed with DI water, and dried at 80 °C in an electric oven to prepare TiO<sub>2</sub>/AC.

### 2.3 Characterization of photocatalyst

The crystalline structure of as-synthesized Ga<sub>2</sub>O<sub>3</sub>/AC was identified by X-ray diffraction (XRD) on a Bruker D8 Advance diffractometer with Cu K $\alpha$  radiation ( $\lambda = 0.15405$  nm) in the region  $2\theta = 5-80^\circ$ . The morphology of composites was observed with a scanning electron microscope (SEM, Hitachi, SU8010). Transmission electron microscopy (TEM) imaging was performed on a FEI Tecnai G2 microscope at an accelerating voltage of 200 kV. The X-ray photoelectron spectroscopy measurements were performed on a Thermo scientific ECALAB 250xi system with Mg K $\alpha$  source. The binding energies were calibrated using that of C 1s (284.6 eV). Nitrogen adsorption and desorption measurements were performed at 77 K using Micromeritics ASAP2020 equipment. The samples were degassed at 200 °C before measurements. Photoluminescence spectra (PLs) of the composite catalysts were recorded using a FLsp 920 luminescence spectrophotometer (Edinburgh) at room temperature with an excitation wavelength of 220 nm. Electron spin resonance (ESR) signals were obtained by using a Bruker ER200-SRC spectrometer at ambient temperature with a Philip lamp of 254 nm as light source. 50  $\mu$ L of sample solutions were put into quartz capillary tubes and sealed. The capillary tubes were inserted in the ESR cavity, and the spectra were recorded during the irradiation at a selected time. All the ESR measurements were performed using the following settings: 20 mW microwave power, 100 G scan range and 1 G field modulation.

### 2.4 Photocatalytic oxidation of CH<sub>4</sub>

Photocatalytic oxidation of CH<sub>4</sub> was implemented with a home-made fixed bed tubular quartz reactor of 500 mL capacity. The schematic diagram of photocatalytic experimental apparatus was shown in Fig. S1 (see, ESI†). All of the photocatalytic experiments were carried out at ambient temperature and pressure unless indicated otherwise. Firstly, 200 mg of composite catalyst was added to 10 mL of H<sub>2</sub>O and ultrasonicated for 20 min. The aqueous suspension was then coated uniformly on the surface of five glass sheets (each glass sheet is 2 cm  $\times$  8 cm), followed by drying at 60 °C until the water was completely removed. The as-obtained supported catalysts were horizontally put into the middle of the tubular reactor. Then, the reactor was vacuumed repeatedly to remove H<sub>2</sub>O and CO<sub>2</sub> that adsorbed on the surface of catalysts and reactor inner-wall. CH<sub>4</sub>, O<sub>2</sub>, and N<sub>2</sub> were mixed at a certain percentage *via* a gas mixer. The obtained gaseous mixture was used to afford a reactant stream. The initial concentration of CH<sub>4</sub> in the stream was 1.56 mmol L<sup>-1</sup>. Before the irradiation, the reaction system was kept in the dark for 2 h to ensure an adsorption-desorption equilibrium state established between photocatalysts and reactants. Then, the photocatalysts were irradiated using a 10 W Philips low-pressure mercury lamp (with a wavelength centered at 254 nm) located in the middle of the quartz reactor. At a given time interval, 1.0 mL gas was collected from the reactor and analyzed using a Thermo gas chromatograph (GC) with a molecular sieve 13 $\times$  column and a HP-Plot/U capillary column equipped with a thermal conductivity detector and a flame ionization detector. The experimental temperature was maintained at  $25 \pm 1$  °C by recirculating a cooling water system. For comparison, the photocatalytic activity of 15%-TiO<sub>2</sub>/AC was also investigated under the same experimental conditions, as those used for 15%-Ga<sub>2</sub>O<sub>3</sub>/AC.

In general, photocatalytic activity is determined by the formation of radical species, such as photo-holes (h<sup>+</sup>), electrons (e<sup>-</sup>), superoxide (O<sub>2</sub><sup>-</sup>), and <sup>•</sup>OH. Comparative investigations of the effect of active species on the photocatalytic activity were conducted by using scavenger reagents to remove the different radicals. Potassium iodide (KI), potassium dichromate (K<sub>2</sub>Cr<sub>2</sub>O<sub>7</sub>), *tert*-butyl alcohol (TBA), and benzoquinone were employed as scavengers for h<sup>+</sup>, e<sup>-</sup>, O<sub>2</sub><sup>-</sup>, and <sup>•</sup>OH, respectively. Typically, 200 mg of photocatalyst was mixed with 1 mM of the different trapping reagents in 10 mL of water and ultrasonicated for 20 min. Then, the aqueous suspensions were coated onto the glass sheets followed by drying at 60 °C until H<sub>2</sub>O was completely removed. The coated sheets were used in the photocatalytic experiments of CH<sub>4</sub> oxidation as described above.

## 3. Results and discussion

### 3.1 Characterization of $\beta$ -Ga<sub>2</sub>O<sub>3</sub>/AC composites

The crystallographic structure of as-synthesized Ga<sub>2</sub>O<sub>3</sub>/AC composites was investigated by XRD and the results were indicated in Fig. 1, as well as with the XRD patterns of bare Ga<sub>2</sub>O<sub>3</sub> and AC shown for comparison. As can be seen from Fig. 1A, the XRD pattern of AC showed two weak broad peaks at about 24.7°



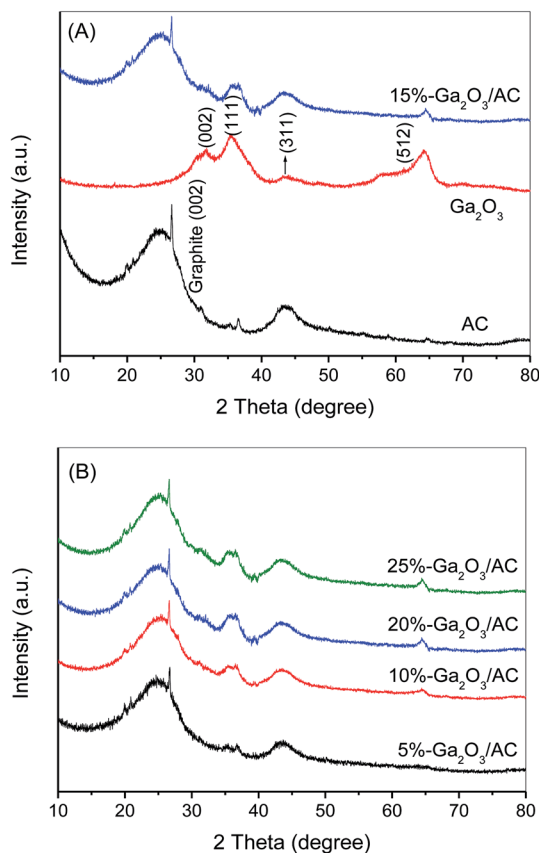


Fig. 1 (A) XRD patterns of bare AC,  $\text{Ga}_2\text{O}_3$  and 15%- $\text{Ga}_2\text{O}_3/\text{AC}$ , (B) XRD patterns of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites with different weight ratios of  $\text{Ga}_2\text{O}_3$ .

and  $43.8^\circ$ , indicating that AC possessed a mainly amorphous structure. A sharp peak at  $26.7^\circ$  assigned to (002) crystallographic plane of hexagonal graphitic structure was also observed,<sup>31</sup> which could be due to small regions of crystallinity in the commercially-obtained AC substrate. Bare  $\text{Ga}_2\text{O}_3$  prepared by the hydrolysis of  $\text{Ga}(\text{NO}_3)_3$  in ammonium solution exhibited the characteristic peaks at  $2\theta$  values of  $31.7^\circ$ ,  $35.4^\circ$ ,  $43.5^\circ$  and  $64.5^\circ$ , which can be indexed as (002), (111), (311) and (512) planes of monoclinic  $\beta\text{-Ga}_2\text{O}_3$  (JCPDS no. 76-0573).<sup>32</sup> It suggests that the as-prepared  $\text{Ga}_2\text{O}_3$  was predominantly nano-sized  $\beta\text{-Ga}_2\text{O}_3$  after the hydrolysis product was calcined at  $600^\circ\text{C}$  for 2 h. This result is well consistent with the previous research.<sup>28</sup> Among the four polymorphs of  $\text{Ga}_2\text{O}_3$  reported in the field of catalysis,  $\beta\text{-Ga}_2\text{O}_3$  is the most stable on thermodynamics and all the other polymorphs can be ultimately transformed into  $\beta\text{-Ga}_2\text{O}_3$  by calcination.<sup>33</sup> As indicated in Fig. 1B, except the characteristic peaks at  $24.7^\circ$ ,  $26.7^\circ$  and  $43.8^\circ$  belonging to amorphous AC, the diffraction peaks at about  $31.7^\circ$ ,  $35.4^\circ$  and  $64.5^\circ$  corresponding to  $\beta\text{-Ga}_2\text{O}_3$  were also observed, which indicated that  $\text{Ga}_2\text{O}_3/\text{AC}$  composites were successfully fabricated *via* the present experimental method. Additionally, it was obvious that the diffraction peak intensity of  $\beta\text{-Ga}_2\text{O}_3$  increased with increasing the amount of  $\text{Ga}_2\text{O}_3$  loaded on AC support.

To investigate the morphology of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites and the distribution of  $\text{Ga}_2\text{O}_3$  particles on the surface of AC, SEM

imaging was carried out and the results were presented in Fig. 2. Fig. 2a showed that AC had a clean and porous surface, which was usually employed as the support owing to its huge specific surface. When the weight ratio of  $\text{Ga}_2\text{O}_3$  was low (*e.g.* 5.0%- $\text{Ga}_2\text{O}_3/\text{AC}$ ), nano- $\text{Ga}_2\text{O}_3$  particles were primarily dispersed on the meso-pore or macro-pore mouths of AC support, as indicated in Fig. 2b. With the increase of  $\text{Ga}_2\text{O}_3$  weight ratios, spherical  $\text{Ga}_2\text{O}_3$  nanoparticles occupied both the pore mouths and the outer surface of AC, as observed from Fig. 2c and d. This is similar to the previously reported  $\text{TiO}_2/\text{AC}$  composites.<sup>34</sup> Additionally, it was clearly seen from Fig. S2 of ESI† that bare  $\text{Ga}_2\text{O}_3$  was composed of nanoparticles with an average size of 6–15 nm, whereas the obvious aggregation could be noted for bare  $\text{Ga}_2\text{O}_3$  particles. By comparing SEM images of  $\text{Ga}_2\text{O}_3/\text{AC}$  and bare  $\text{Ga}_2\text{O}_3$ , it can be easily found that the loading on AC facilitates the uniform distribution of  $\text{Ga}_2\text{O}_3$  nanoparticles.

To further investigate the microstructure of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites, the TEM images were provided and shown in Fig. 3. It is clearly indicated that  $\text{Ga}_2\text{O}_3$  nanoparticles (black dots) with nanosized dimension were uniformly deposited on the surface of AC (gray region), and the large scale agglomerate was not detected in 5.0%- $\text{Ga}_2\text{O}_3/\text{AC}$  and 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  composites (Fig. 3a and b). A high-resolution TEM image of 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  was shown in Fig. 3d. The lattice fringes of  $d = 0.282$  nm and  $d = 0.255$  nm matched those of (002) and (111) crystallographic planes of  $\beta\text{-Ga}_2\text{O}_3$ , respectively.<sup>35</sup> The intimate contact of activated carbon with  $\beta\text{-Ga}_2\text{O}_3$  lattice was also evidenced from the HRTEM image. However, when the weight ratio of  $\text{Ga}_2\text{O}_3$  increased up to 25%, the as-formed  $\text{Ga}_2\text{O}_3$  particles were inclined to agglomerate (Fig. 3c). It indicates that the  $\text{Ga}_2\text{O}_3$  nanoparticles are easier to agglomerate on the surface of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites with increasing  $\text{Ga}_2\text{O}_3$  weight ratios. It is well known that the catalytic activities of nanocomposite photocatalysts strongly depend on the distribution of active components on the surface of support. Compared with  $\text{Ga}_2\text{O}_3$  particles deposited homogeneously on the surface of 15%- $\text{Ga}_2\text{O}_3/\text{AC}$ , the agglomerated  $\text{Ga}_2\text{O}_3$  nanoparticles in 25%- $\text{Ga}_2\text{O}_3/\text{AC}$  composites may hamper the light incidence on the photoreactive sites and consequently reduce the photocatalytic oxidation efficiency.

The chemical components and surface chemical states of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites were confirmed using XPS, and the results were presented in Fig. 4. The typical XPS survey spectrum with energy ranging from 0 to 1200 eV obtained from 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  was shown in Fig. 4a, which reveal the peaks of the core level from Ga 2p, Ga 3d, Ga LMM Auger peak, C 1s and O 1s. The energy peaks positioned at 1149.2 and 1121.5 eV in Fig. 4b are known to stem from Ga 2p<sub>1/2</sub> and Ga 2p<sub>3/2</sub>, representing the Ga–O bonding.<sup>36</sup> The energy peak of Ga 3d centered at 23.6 eV can be ascribed to the presence of gallium in  $\beta\text{-Ga}_2\text{O}_3$  (Fig. 4a). The O1s XPS signal observed at a binding energy of 532.4 eV (Fig. 4c) corresponded to the characteristic peak of  $\beta\text{-Ga}_2\text{O}_3$ .<sup>37</sup> The XPS analysis confirmed that the as-prepared  $\text{Ga}_2\text{O}_3$  was mainly nanosized  $\beta\text{-Ga}_2\text{O}_3$ , which accords with the XRD measurement. Fig. 4d showed the C 1s peak of 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  was at 284.6 eV, which was mainly owed to the AC and the pollutant carbon from the XPS instrument.<sup>38</sup> Besides, the





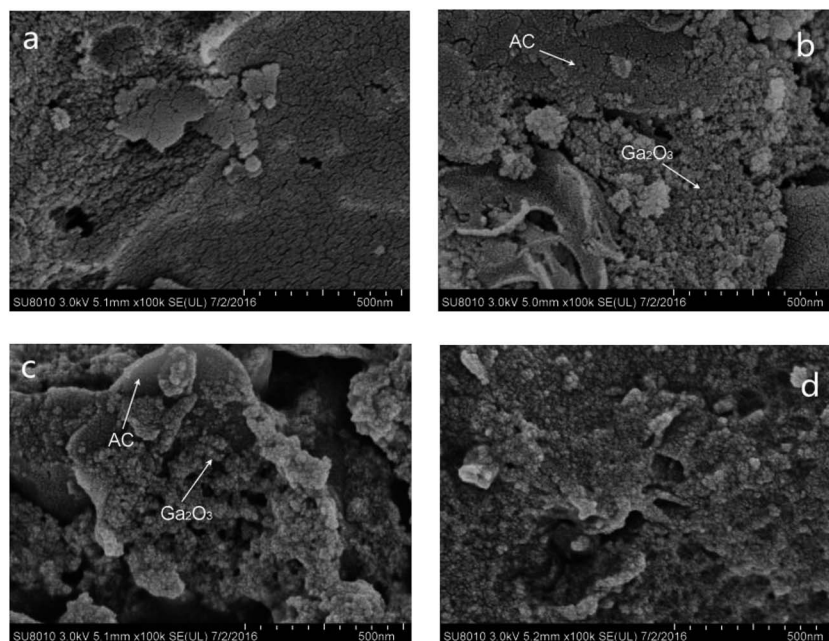


Fig. 2 SEM images of (a) AC, (b) 5.0%-Ga<sub>2</sub>O<sub>3</sub>/AC, (c) 15%-Ga<sub>2</sub>O<sub>3</sub>/AC, and (d) 25%-Ga<sub>2</sub>O<sub>3</sub>/AC.

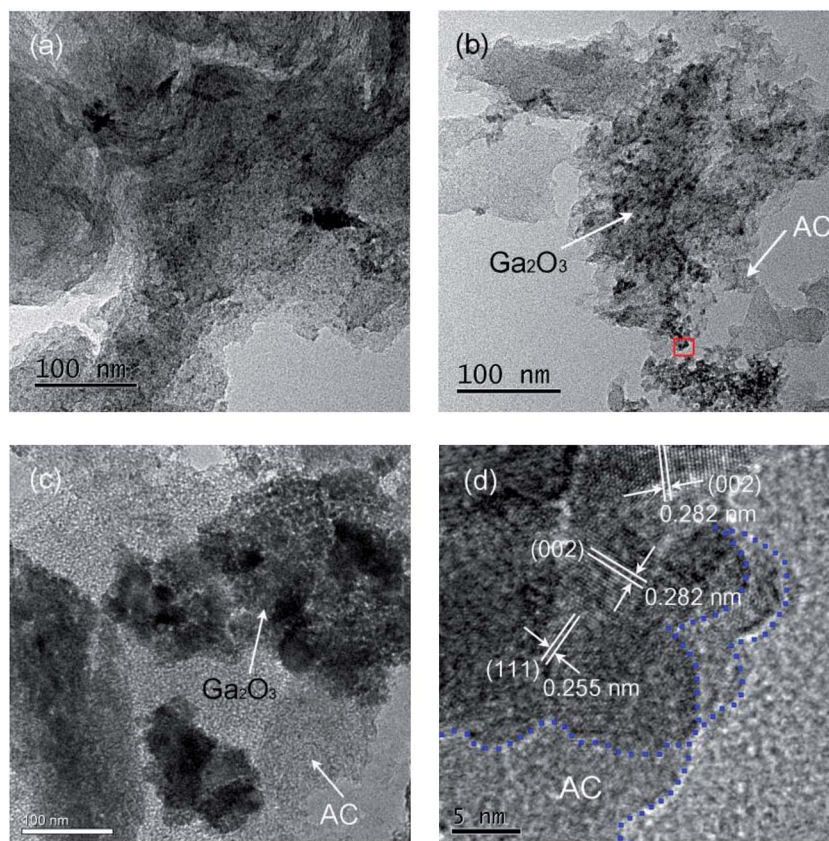


Fig. 3 TEM images of (a) 5.0%-Ga<sub>2</sub>O<sub>3</sub>/AC, (b) 15%-Ga<sub>2</sub>O<sub>3</sub>/AC, (c) 25%-Ga<sub>2</sub>O<sub>3</sub>/AC, and (d) high-resolution TEM image of 15%-Ga<sub>2</sub>O<sub>3</sub>/AC.

atomic contents of Ga and C in different Ga<sub>2</sub>O<sub>3</sub>/AC nanocomposite samples were calculated from XPS peak areas, which can be converted to the weight ratios of Ga<sub>2</sub>O<sub>3</sub> to AC. As

indicated in Table 1, the calculated weight ratios for Ga<sub>2</sub>O<sub>3</sub> and AC are closely equal to the adding ratios in the preparation process, implying that gallium nitrate hydrate can be



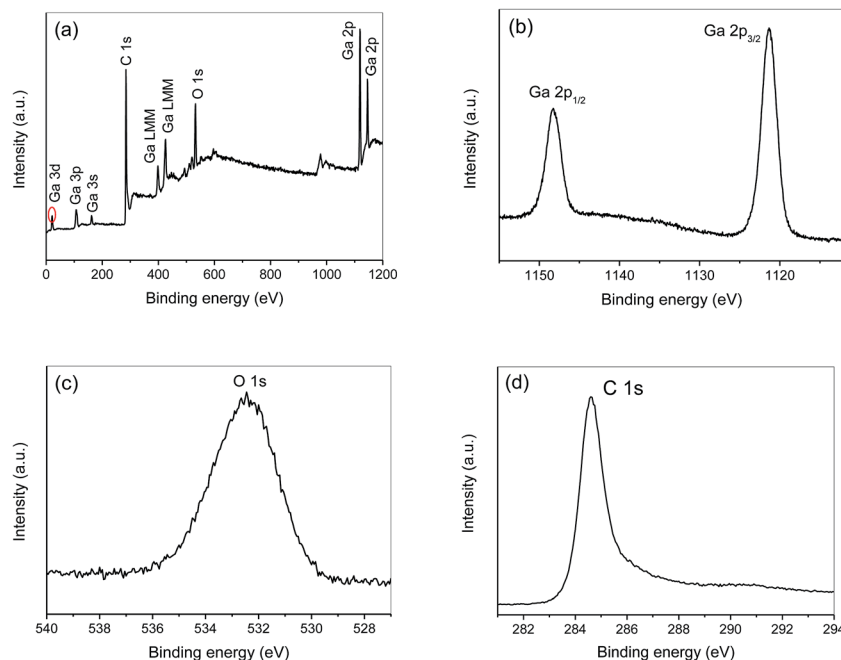


Fig. 4 XPS of 15%-Ga<sub>2</sub>O<sub>3</sub>/AC nanocomposite sample: (a) survey spectrum, (b) Ga 2p, (c) O 1s, and (d) C 1s.

**Table 1** The calculated weight ratios of Ga<sub>2</sub>O<sub>3</sub> to AC based on XPS measurements and textural characteristics of bare Ga<sub>2</sub>O<sub>3</sub> and Ga<sub>2</sub>O<sub>3</sub>/AC composites obtained from N<sub>2</sub> adsorption–desorption experiments<sup>a</sup>

Samples	Weight ratio of Ga <sub>2</sub> O <sub>3</sub> to AC	$S_{\text{BET}}$ (m <sup>2</sup> g <sup>−1</sup> )	$V_{\text{T}}$ (cm <sup>3</sup> g <sup>−1</sup> )	$V_{\text{M}}$ (cm <sup>3</sup> g <sup>−1</sup> )	Pore size (nm)
AC		907	0.618	0.269	1.61
Ga <sub>2</sub> O <sub>3</sub>		101	0.125	0.017	3.85
5%-Ga <sub>2</sub> O <sub>3</sub> /AC	5.6%	836	0.420	0.120	2.26
10%-Ga <sub>2</sub> O <sub>3</sub> /AC	10.9%	758	0.302	0.056	3.09
15%-Ga <sub>2</sub> O <sub>3</sub> /AC	14.3%	685	0.237	0.025	3.48
20%-Ga <sub>2</sub> O <sub>3</sub> /AC	21.0%	652	0.226	0.023	3.53
25%-Ga <sub>2</sub> O <sub>3</sub> /AC	26.4%	630	0.219	0.022	3.51

<sup>a</sup>  $S_{\text{BET}}$ , specific surface area obtained by BET equation;  $V_{\text{T}}$ , total pore volume;  $V_{\text{M}}$ , micropore volume; average pore size from pore size distribution by BJH method.

completely converted to Ga<sub>2</sub>O<sub>3</sub> *via* the as-mentioned hydrolysis method.

Since heterogeneous photocatalysis is generally influenced by the specific surface area of catalysts, the pore structure and BET surface area of the synthesized composites were studied on the basis of N<sub>2</sub> adsorption and desorption measurements. Fig. 5 showed N<sub>2</sub> adsorption–desorption isotherms of bare Ga<sub>2</sub>O<sub>3</sub> and 15%-Ga<sub>2</sub>O<sub>3</sub>/AC and the corresponding pore size distribution was given in the inset of Fig. 5. According to the IUPAC classification, the adsorption isotherms of bare Ga<sub>2</sub>O<sub>3</sub> and 15%-Ga<sub>2</sub>O<sub>3</sub>/AC were of type IV isotherm, indicating the presence of mesoporous structures. The structural and textural characteristics of as-prepared composites can be obtained from N<sub>2</sub> adsorption–desorption isotherms and the corresponding data were summarized in Table 1. For bare Ga<sub>2</sub>O<sub>3</sub>, the BET specific surface area ( $S_{\text{BET}}$ ) was 101 m<sup>2</sup> g<sup>−1</sup> and the average pore size was 3.85 nm with a narrow distribution of pore size. As indicated in Table 1, bare AC had a large  $S_{\text{BET}}$  of

907 m<sup>2</sup> g<sup>−1</sup> and high total pore volume of 0.618 cm<sup>3</sup> g<sup>−1</sup> because of the porous property. After introducing Ga<sub>2</sub>O<sub>3</sub> particles into AC matrix,  $S_{\text{BET}}$ , total pore volume and micropore volume of the obtained Ga<sub>2</sub>O<sub>3</sub>/AC composites decreased significantly. Whereas the average pore diameter in the composites increased slightly, compared to bare AC, which could be due to the formation of meso-pores or macro-pores in the channels between the deposited Ga<sub>2</sub>O<sub>3</sub> nanoparticles on the surface of AC. The decrease in micropore volume of Ga<sub>2</sub>O<sub>3</sub>/AC could be ascribed to the effects of meso-pores blocking by deposited Ga<sub>2</sub>O<sub>3</sub>, since these meso-pores acted as the primary passageway to microporous regions in AC. On the other hand, small grain size and uniform distribution of Ga<sub>2</sub>O<sub>3</sub> particles could inhibit the reduction of  $S_{\text{BET}}$  and pore volume of Ga<sub>2</sub>O<sub>3</sub>/AC composites to some extent. A larger  $S_{\text{BET}}$  can give rise to more active adsorption sites and photocatalytic reaction centers, which means higher  $S_{\text{BET}}$  will be beneficial to improving the photocatalytic activity.<sup>39</sup>



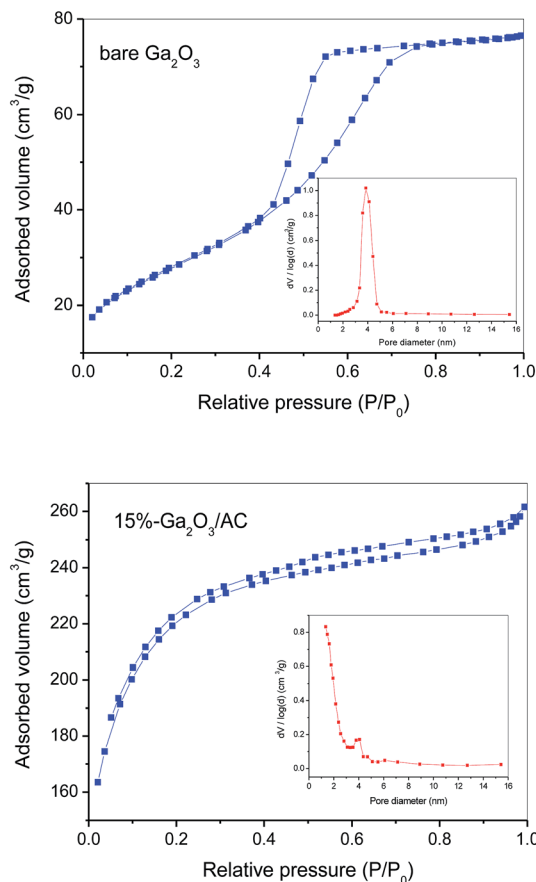


Fig. 5 Nitrogen adsorption-desorption BET isotherms and pore size distribution curves (inset) of bare  $\text{Ga}_2\text{O}_3$  and 15%- $\text{Ga}_2\text{O}_3/\text{AC}$ .

### 3.2 Photocatalytic properties of $\text{Ga}_2\text{O}_3/\text{AC}$ composites

Surface adsorption is the precondition of photocatalytic reaction and strong adsorption of target reactants facilitates the catalytic oxidation between the adsorbed reactants and surface active species. Therefore, the dark-adsorption of  $\text{CH}_4$  on the surface of as-synthesized samples was investigated firstly. The adsorption capacity of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites as well as bare  $\text{Ga}_2\text{O}_3$  and AC was estimated by studying the removal rate of  $\text{CH}_4$  in a fixed-bed reactor and the results were presented in Fig. 6. For bare AC, the removal of  $\text{CH}_4$  increased gradually with the increase of adsorption time and about 45.1% of the initial  $\text{CH}_4$  was removed until reaching an adsorption equilibrium at the end of 120 min in the dark. Whereas, for bare  $\text{Ga}_2\text{O}_3$ , only 8.9% of the initial  $\text{CH}_4$  was removed in the dark-adsorption process. In the case of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites, the initial removal of  $\text{CH}_4$  driven by dark adsorption was lower than unmodified AC. It can be obtained from Fig. 6B that the adsorption-induced removal percentages of  $\text{CH}_4$  were 20.4%, 18.1%, 16.2%, 15.5%, and 14.6% for 5%- $\text{Ga}_2\text{O}_3/\text{AC}$ , 10%- $\text{Ga}_2\text{O}_3/\text{AC}$ , 15%- $\text{Ga}_2\text{O}_3/\text{AC}$ , 20%- $\text{Ga}_2\text{O}_3/\text{AC}$ , and 25%- $\text{Ga}_2\text{O}_3/\text{AC}$ , respectively. It was clearly found that the adsorption-induced removal of  $\text{CH}_4$  decreased gradually with the increased  $\text{Ga}_2\text{O}_3$  loading. The results could be explained by SEM images and  $\text{N}_2$  adsorption-desorption experimental results, as indicated in Fig. 2 and Table 1. SEM images in Fig. 2 demonstrated that most

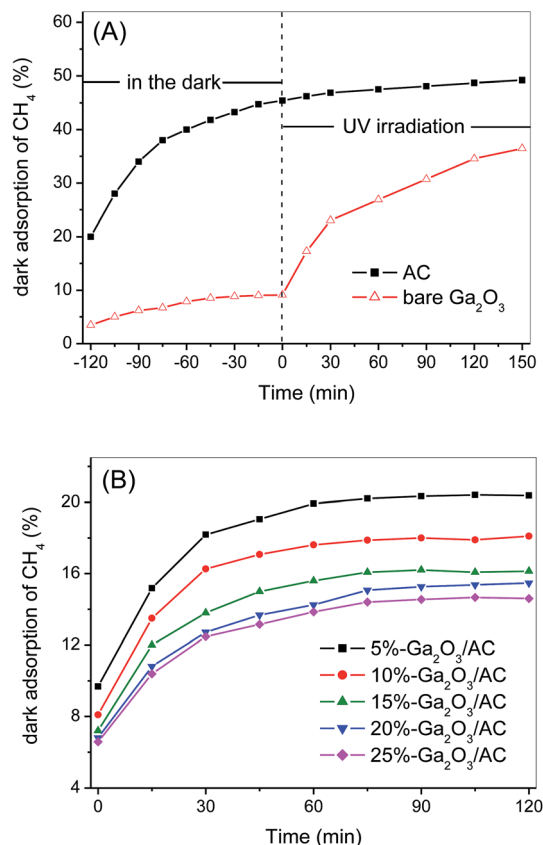


Fig. 6 The dark adsorption of  $\text{CH}_4$  over (A) bare AC and  $\text{Ga}_2\text{O}_3$ , (B) different  $\text{Ga}_2\text{O}_3/\text{AC}$  composites.

of AC surface was covered by  $\text{Ga}_2\text{O}_3$  nanoparticles. It would result in a negative effect on the adsorption ability of AC, especially for the internal adsorption sites in AC because of the pore blocking by  $\text{Ga}_2\text{O}_3$  particles.

In the present system,  $\text{CH}_4$  removal *via* the gas-solid catalytic reaction can be divided into two steps. One is the above-mentioned adsorption process in the darkness, the other step is photocatalytic oxidation process under UV illumination. For the unmodified AC, only 4.0% of  $\text{CH}_4$  was further removed after UV irradiation for 150 min, as indicated in Fig. 6A. In contrast to AC, after dark adsorption for 120 min,  $\text{CH}_4$  could be significantly decomposed by the photocatalytic oxidation over bare  $\text{Ga}_2\text{O}_3$ . It can be seen from Fig. 6A that  $\text{CH}_4$  removal increased dramatically with prolonging the time of UV illumination and  $\text{CH}_4$  removal efficiency reached approximately 36.5% after 150 min irradiation, which was mainly attributed to the photocatalytic oxidation process.

To investigate the kinetic behavior of  $\text{CH}_4$  oxidation, the concentration data of photocatalytic  $\text{CH}_4$  degradation were normalized by the initial concentration at the start of illumination, which was also regarded as the equilibrium concentration of dark-adsorption. The as-obtained degradation percentage ( $C/C_0$ ) of  $\text{CH}_4$  as a function of irradiation time was presented in Fig. 7A. The blank experiment in Fig. 7A referred to the photocatalytic oxidation of  $\text{CH}_4$  under UV irradiation in the absence of  $\text{Ga}_2\text{O}_3$  or  $\text{Ga}_2\text{O}_3/\text{AC}$  composites. No obvious





photocatalytic oxidation of CH<sub>4</sub> was observed after illumination for 150 min in the absence of catalysts. Careful analysis of CH<sub>4</sub> photo-oxidation revealed that the reactions follow pseudo-first-order kinetics and the integrated rate equation can be expressed by:

$$\ln\left(\frac{C_0}{C}\right) = k't$$

where  $k'$  represents the pseudo-first-order rate constant (min<sup>-1</sup>). It is valid for the comparison of various composite photocatalysts since the as-obtained photocatalytic activity is independent of dark-adsorption. Fig. 7B described the liner relationship between  $\ln(C_0/C)$  and illumination time  $t$ , where the slopes of lines denoted pseudo-first-order rate constant  $k'$ . The corresponding data were summarized in Table 2.

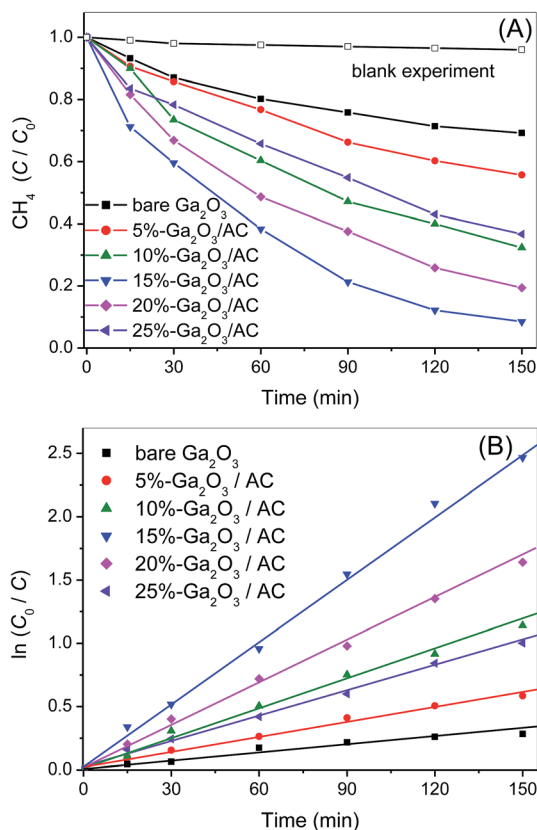
The photocatalytic oxidation of CH<sub>4</sub> primarily proceeded on the outer surface of catalysts. Thus, the weight proportion and distribution of Ga<sub>2</sub>O<sub>3</sub> particles on the exterior surface of Ga<sub>2</sub>O<sub>3</sub>/AC are the crucial factors in CH<sub>4</sub> oxidation. The effect of Ga<sub>2</sub>O<sub>3</sub> weight proportion on CH<sub>4</sub> oxidation rate was shown in Fig. 7. From Fig. 7A, it can be found the oxidation rate of CH<sub>4</sub> increased with the increase of irradiation time, possibly because of continuous formation of active radicals upon the surface of irradiated Ga<sub>2</sub>O<sub>3</sub> particles. Photocatalytic CH<sub>4</sub> oxidation rates of as-synthesized composites were greatly

**Table 2** First-order kinetic constants and relative coefficients toward photocatalytic oxidation of methane with bare Ga<sub>2</sub>O<sub>3</sub> and Ga<sub>2</sub>O<sub>3</sub>/AC composites

Samples	$k'$ (min <sup>-1</sup> )	$R^2$
Bare Ga <sub>2</sub> O <sub>3</sub>	0.0023	0.9775
5%-Ga <sub>2</sub> O <sub>3</sub> /AC	0.0039	0.9949
10%-Ga <sub>2</sub> O <sub>3</sub> /AC	0.0081	0.9959
15%-Ga <sub>2</sub> O <sub>3</sub> /AC	0.0171	0.9981
20%-Ga <sub>2</sub> O <sub>3</sub> /AC	0.0113	0.9987
25%-Ga <sub>2</sub> O <sub>3</sub> /AC	0.0067	0.9970

dependent on the weight ratio of Ga<sub>2</sub>O<sub>3</sub> to AC. It could be obtained from Fig. 7B, the pseudo-first-order rate constant of photocatalytic oxidation CH<sub>4</sub> over bare Ga<sub>2</sub>O<sub>3</sub>, 5%-Ga<sub>2</sub>O<sub>3</sub>/AC, 10%-Ga<sub>2</sub>O<sub>3</sub>/AC, 15%-Ga<sub>2</sub>O<sub>3</sub>/AC, 20%-Ga<sub>2</sub>O<sub>3</sub>/AC, and 25%-Ga<sub>2</sub>O<sub>3</sub>/AC was 0.0023, 0.0039, 0.0081, 0.0171, 0.0113, and 0.0067 min<sup>-1</sup>, respectively. The photocatalytic oxidation rate firstly increased with increasing the weight ratio of Ga<sub>2</sub>O<sub>3</sub> to AC, and then reduced when the weight ratio was higher than 15%. The similar result has been reported in TiO<sub>2</sub>/AC photocatalytic system.<sup>39</sup> When the weight ratio of Ga<sub>2</sub>O<sub>3</sub> was low, photocatalytic rate of CH<sub>4</sub> oxidation was also low, which might be due to the limited Ga<sub>2</sub>O<sub>3</sub> particles loaded on the composites. With the increase of Ga<sub>2</sub>O<sub>3</sub> loading, more Ga<sub>2</sub>O<sub>3</sub> were deposited on the surface of AC. As a result, photo-reactive sites available on the surface of catalysts increased, which is beneficial for the gas-solid catalytic reaction of CH<sub>4</sub> oxidation. It was clearly seen from Fig. 7 that 15%-Ga<sub>2</sub>O<sub>3</sub>/AC exhibited highest oxidation rate of CH<sub>4</sub>, revealing that appropriate weight ratio of Ga<sub>2</sub>O<sub>3</sub> to AC was able to well disperse Ga<sub>2</sub>O<sub>3</sub> nanoparticles and thus improve the migration of photogenerated electrons. This facilitated the separation of photoinduced electrons and holes, which could efficiently promote photocatalytic rate. However, when the weight proportion of Ga<sub>2</sub>O<sub>3</sub> exceeded 15%, photocatalytic oxidation rates decreased with the increasing of Ga<sub>2</sub>O<sub>3</sub> weight proportion. The reason could be due to the fact that a certain amount of nanosized Ga<sub>2</sub>O<sub>3</sub> particles aggregated on the surface of Ga<sub>2</sub>O<sub>3</sub>/AC, which would reduce the efficient light absorption and reactive sites for photocatalytic oxidation. Besides, the reduction of  $S_{\text{BET}}$  and pore volume (as shown in Table 1) resulted in the decrease of CH<sub>4</sub> adsorption on the surface of Ga<sub>2</sub>O<sub>3</sub>/AC, which partly reduced the photo-activity for CH<sub>4</sub> oxidation. The results further indicate that the weight proportion and dispersibility of Ga<sub>2</sub>O<sub>3</sub> particles on the surface of composite photocatalysts are crucial for the improved photocatalytic activity.

To further understand the oxidation process of CH<sub>4</sub> removal over as-prepared Ga<sub>2</sub>O<sub>3</sub>/AC samples, the effect of light intensity on the photocatalytic activity was investigated. Photocatalytic oxidation of methane upon the optimal composites 15%-Ga<sub>2</sub>O<sub>3</sub>/AC was normalized by the initial concentration at the end of dark adsorption. As indicated in Fig. S3 of ESI<sup>†</sup>, the CH<sub>4</sub> removal driven by photocatalytic oxidation process on 15%-Ga<sub>2</sub>O<sub>3</sub>/AC was proportional to the irradiation intensity. This obviously demonstrates that a higher intensity of irradiation gives rise to a more efficient removal of CH<sub>4</sub>, suggesting the



**Fig. 7** (A) Photocatalytic oxidation of CH<sub>4</sub> over bare Ga<sub>2</sub>O<sub>3</sub> and Ga<sub>2</sub>O<sub>3</sub>/AC composites under UV irradiation, (B) pseudo-first-order reaction kinetics curves of photocatalytic CH<sub>4</sub> oxidation over as-synthesized samples.





incident light intensity plays an important role in  $\text{CH}_4$  photocatalytic oxidation system. Under UV irradiation, stronger light intensities can excite more  $\text{Ga}_2\text{O}_3$  catalysts and generate more charge carriers or active radical species, leading to higher  $\text{CH}_4$  oxidation rates. Meanwhile, the results confirm that the methane removal over  $\text{Ga}_2\text{O}_3/\text{AC}$  composite photocatalyst is truly driven by a photocatalytic oxidation process.

Photocatalytic oxidation of  $\text{CH}_4$  under different initial concentrations was also carried out and the results were indicated in Fig. 8. The photo-oxidation reactions under various initial  $\text{CH}_4$  concentrations also followed pseudo-first-order kinetics and the apparent rate constants  $k'$  obtained from Langmuir-Hinshelwood model were 0.0171, 0.0134, 0.0102, 0.0070 and 0.0051  $\text{min}^{-1}$ , respectively, with increasing the initial  $\text{CH}_4$  concentration from 1.56 to 7.90  $\text{mmol L}^{-1}$  (Fig. 8B). This clearly demonstrates that photocatalytic technique is more competent for eliminating low concentration of  $\text{CH}_4$ . It is totally different from traditional thermal catalysis, which usually exhibits poor catalytic activity when the concentration of reactant is low.

For the photocatalytic methane oxidation, the photo-generated holes or the lattice oxygen activated by photo-holes are considered as the primary active species toward abstracting H from  $\text{CH}_4$ .<sup>40</sup> This step is closely related to energy and intensity of irradiation. That is, when fixing the irradiation

conditions, the reaction rates are primarily dependent on  $\text{CH}_4$  initial concentration, and proceed more quickly for lower concentration. To elucidate the excellent performance of  $\text{Ga}_2\text{O}_3$ -based photocatalysts for  $\text{CH}_4$  oxidation, dark-adsorption and photocatalytic process of commercial P25 and 15%- $\text{TiO}_2/\text{AC}$  were also investigated under the same experimental conditions. Commercial P25, as a recognized benchmark photocatalyst, is selected to compare with bare  $\text{Ga}_2\text{O}_3$ . As shown in Fig. 9A, only 5.7% of the initial  $\text{CH}_4$  was removed over commercial P25 at the end of dark-adsorption, which was slightly lower than that of bare  $\text{Ga}_2\text{O}_3$  (8.9%). It can be due to the smaller  $S_{\text{BET}}$  of P25 ( $\sim 50 \text{ m}^2 \text{ g}^{-1}$ ), compared to as-prepared  $\text{Ga}_2\text{O}_3$  ( $\sim 101 \text{ m}^2 \text{ g}^{-1}$ ). 15%- $\text{TiO}_2/\text{AC}$  composite was also prepared *via in situ* synthesis strategy, as presented in the Experimental section. Similar to the synthesis of  $\text{Ga}_2\text{O}_3/\text{AC}$  composites, the preparation of nanosized  $\text{TiO}_2$  and the compositing of as-prepared  $\text{TiO}_2$  with AC were simultaneously carried out. The XRD pattern and SEM image of 15%- $\text{TiO}_2/\text{AC}$  sample were depicted in Fig. S4 and S5 of ESI.† The characteristic diffraction peaks at  $25.4^\circ$ ,  $37.9^\circ$ ,  $48.1^\circ$ ,  $54.7^\circ$  and  $63.1^\circ$  were observed, indicating that as-obtained  $\text{TiO}_2$  was anatase phase. SEM images of 15%- $\text{TiO}_2/\text{AC}$  showed that  $\text{TiO}_2$  nanoparticles were uniformly dispersed and loaded upon the surface of AC. It can be found from Fig. 9B that although 15%- $\text{TiO}_2/\text{AC}$  and 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  exhibited similar adsorption

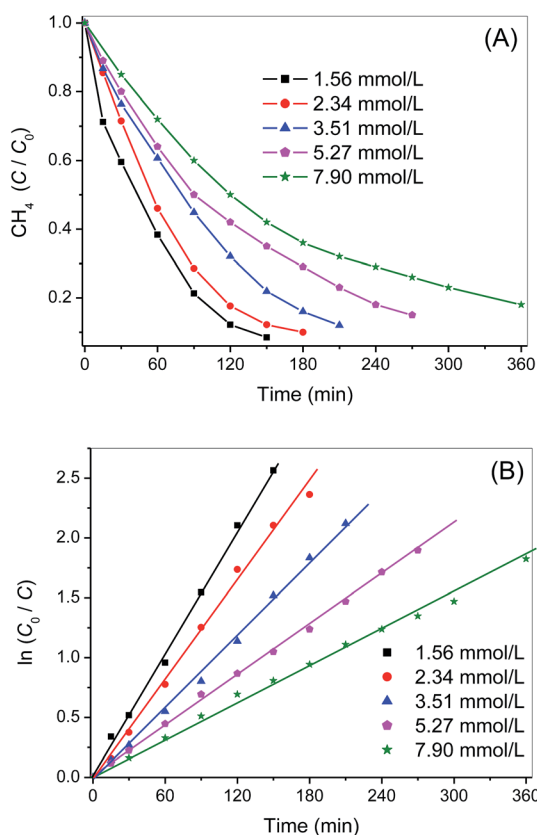


Fig. 8 (A) Time evolution of methane photocatalytic oxidation over 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  under UV illumination with various initial  $\text{CH}_4$  concentrations, (B) the corresponding pseudo-first-order reaction kinetics plots of photocatalytic  $\text{CH}_4$  oxidation.

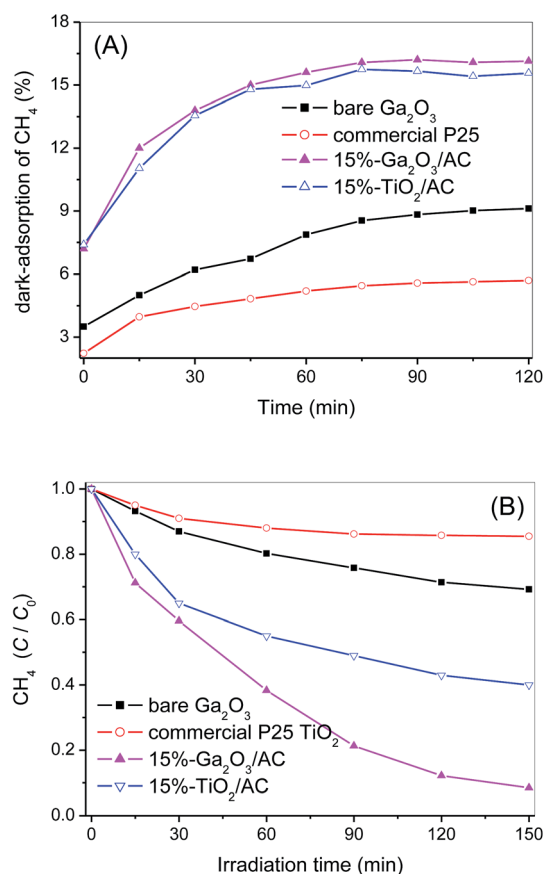


Fig. 9 (A) Dark-adsorption of  $\text{CH}_4$  over bare  $\text{Ga}_2\text{O}_3$ , commercial P25, 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  and 15%- $\text{TiO}_2/\text{AC}$ ; (B) photocatalytic oxidation of  $\text{CH}_4$  upon bare  $\text{Ga}_2\text{O}_3$ , commercial P25, 15%- $\text{Ga}_2\text{O}_3/\text{AC}$  and 15%- $\text{TiO}_2/\text{AC}$  under UV irradiation.



capacity for CH<sub>4</sub>, the photocatalytic oxidation of CH<sub>4</sub> over 15%-Ga<sub>2</sub>O<sub>3</sub>/AC was significantly greater than 15%-TiO<sub>2</sub>/AC. It suggests that high catalytic performance of Ga<sub>2</sub>O<sub>3</sub>/AC cannot be simply explained by the surface adsorption. CH<sub>4</sub> removal induced by photocatalytic oxidation over bare Ga<sub>2</sub>O<sub>3</sub> and Ga<sub>2</sub>O<sub>3</sub>/AC was higher than that over P25 and TiO<sub>2</sub>/AC. It could be associated with the band gap structures of Ga<sub>2</sub>O<sub>3</sub> and TiO<sub>2</sub>. For semiconductor TiO<sub>2</sub>, the conduction band and valence band consist of Ti 3d and O 2p orbitals, respectively. In the case of Ga<sub>2</sub>O<sub>3</sub>, the valence band is composed of O 2p orbital, whereas the conduction band consists of hybridized Ga 4s4p orbital. The bandgap energy of Ga<sub>2</sub>O<sub>3</sub> is 4.8 eV, much wider than that of TiO<sub>2</sub> (3.2 eV). Additionally, the reported valence-band potential of Ga<sub>2</sub>O<sub>3</sub> is −7.75 eV, which is lower than that of TiO<sub>2</sub> −7.41 eV. Whereas, the conduction-band potential of Ga<sub>2</sub>O<sub>3</sub> is −2.95 eV, which is higher than that of TiO<sub>2</sub> −4.21 eV.<sup>28,29</sup> As a result, the photo-holes and photo-electrons generated on Ga<sub>2</sub>O<sub>3</sub> possess stronger redox ability than those formed on TiO<sub>2</sub>. The intrinsic energy-band structure of Ga<sub>2</sub>O<sub>3</sub> contributes to the excellent photocatalytic activity for CH<sub>4</sub> oxidation.

To examine the mineralization ratio during photocatalytic CH<sub>4</sub> oxidation, the production of CO<sub>2</sub> over 15%-Ga<sub>2</sub>O<sub>3</sub>/AC photocatalysts was detected and the corresponding result was presented in Fig. S6 of ESI.† Before UV light was turned on, no CO<sub>2</sub> was detected, which indicated the dark-adsorption process cannot produce CO<sub>2</sub>. After the light was turned on, the concentration of CH<sub>4</sub> decreased significantly with the irradiation time. Meanwhile, the amount of CO<sub>2</sub> increased gradually and around 0.93 mmol L<sup>−1</sup> of CO<sub>2</sub> was produced from CH<sub>4</sub> photooxidation under UV irradiation for 150 min. Besides, no other intermediate products, such as CO or ethane, were detected by GC during the CH<sub>4</sub> photocatalytic oxidation. Carbon mass balance of 79.0% could be obtained based on the proportion of the sum of remaining CH<sub>4</sub> (0.105 mmol L<sup>−1</sup>) and produced CO<sub>2</sub> (0.93 mmol L<sup>−1</sup>) to carbon input (1.31 mmol L<sup>−1</sup> CH<sub>4</sub> at the end of adsorption process). This suggests that about 79.0% CH<sub>4</sub> is mineralized to CO<sub>2</sub> after UV irradiation for 150 min.

The stability or recyclability of a catalyst is an extremely crucial parameter for practical utilization. To test the stability of as-prepared Ga<sub>2</sub>O<sub>3</sub>/AC photocatalysts, a cycling CH<sub>4</sub> photo-oxidation test over the optimal composite 15%-Ga<sub>2</sub>O<sub>3</sub>/AC was thus performed and the results were indicated in Fig. 10. After six cycles, the activity of 15%-Ga<sub>2</sub>O<sub>3</sub>/AC almost remained unchanged. Moreover, the crystal structure and chemical composition of recycled 15%-Ga<sub>2</sub>O<sub>3</sub>/AC sample were also investigated by XRD and XPS analysis. No noticeable differences between the freshly made and the repeatedly used samples were observed from Fig. S7 of ESI.† The results demonstrate Ga<sub>2</sub>O<sub>3</sub>/AC composites are stable and can be recycled toward CH<sub>4</sub> photocatalytic oxidation.

### 3.3 Photocatalytic mechanism of CH<sub>4</sub> oxidation over Ga<sub>2</sub>O<sub>3</sub>/AC composites

Photoluminescence (PL) generally arises from the charge recombination process of photoinduced electron and hole and

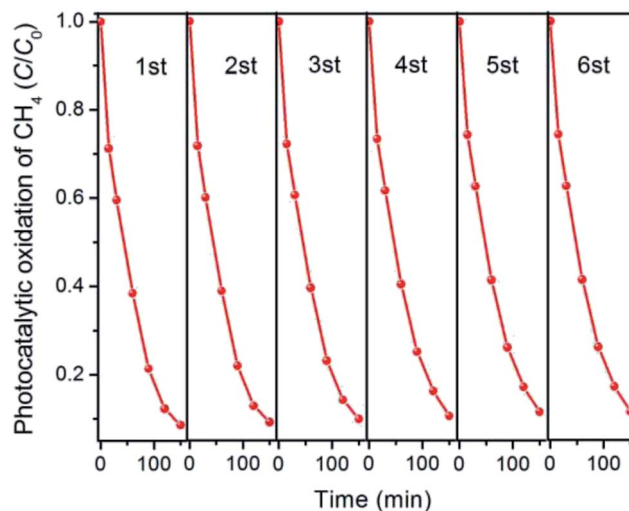


Fig. 10 Recycled test of photocatalytic oxidation of CH<sub>4</sub> over 15%-Ga<sub>2</sub>O<sub>3</sub>/AC.

thus the intensity of PL peak can represent the recombination extent of photogenerated charges. Low PL intensity usually demonstrates low recombination degree and efficient separation of h<sup>+</sup> and e<sup>−</sup>. Fig. 11 showed the PL spectra of bare Ga<sub>2</sub>O<sub>3</sub> and various Ga<sub>2</sub>O<sub>3</sub>/AC composites. The as-prepared samples exhibited the same PL peaks and similar curve shapes, which indicated introduction of AC did not generate new luminescence phenomena but the weight ratio of Ga<sub>2</sub>O<sub>3</sub> indeed affected the PL intensity. The major luminescence signals were observed in the wavelength range of 350–480 nm. The peak at around 370 nm and 400 nm could be assigned to the recombination of self-trapped excitons, which mainly originated from the band edge emission.<sup>41,42</sup> Furthermore, based on the previous reports, β-Ga<sub>2</sub>O<sub>3</sub> contains two kinds of Ga<sup>3+</sup> ions.<sup>41,42</sup> One is Ga<sup>3+</sup> ion in the tetrahedral site coordinated by four oxygen atoms and the other is that in the octahedral site coordinated by six oxygen atoms. An emission centered at 465 nm might be derived from the recombination of electrons trapped by oxygen vacancy and holes generated by either gallium vacancy or gallium–oxygen

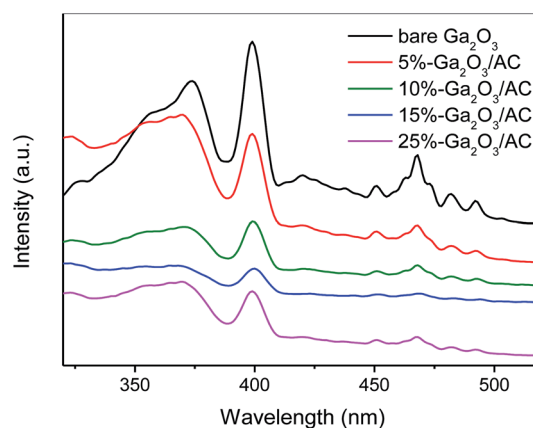


Fig. 11 Photoluminescence spectra of bare Ga<sub>2</sub>O<sub>3</sub> and Ga<sub>2</sub>O<sub>3</sub>/AC composites.



vacancy pairs.<sup>41,42</sup> These vacancies could be formed by the thermal treatment during the synthesis process.

More importantly, the incorporation of AC led to the decrease in the intensity of PL spectra, which suggests that the composite photocatalysts possess low recombination of  $h^+$  and  $e^-$ . The intensity of luminescence peaks decreased in the order of bare  $Ga_2O_3 > 5\%-Ga_2O_3/AC > 10\%-Ga_2O_3/AC \approx 25\%-Ga_2O_3/AC > 15\%-Ga_2O_3/AC$ . When the weight ratio of  $Ga_2O_3$  was low,  $Ga_2O_3$  particles were mainly dispersed on the meso-pore or macro-pore mouths of AC, as presented in Fig. 2b, resulting in the moderate decrease of PL intensity. As the weight ratio of  $Ga_2O_3$  to AC increased, the PL intensity of  $Ga_2O_3/AC$  composites gradually decreased. A lower PL intensity usually indicates a slower recombination rate and higher separation efficiency of photoinduced charge carriers. 15%- $Ga_2O_3/AC$  sample exhibited lowest PL intensity, which could be due to the highly dispersed  $Ga_2O_3$  nanoparticles supported onto the surface of AC. It was beneficial for the separation of photo-induced electron/hole pairs and consequently improved the photocatalytic activity. However, when the weight ratio of  $Ga_2O_3$  was too high, nano-sized  $Ga_2O_3$  particles could aggregate on the surface of AC, which reduced the efficient light absorption and separation of photogenerated  $h^+$  and  $e^-$ .

The photocatalytic oxidation of methane generally involves the surface reactions of photogenerated holes and electrons, which may also produce oxidizing species, such as  $O_2^{\cdot-}$  and  $\cdot OH$  to further the oxidation reactions. To identify the generation of reactive species and investigate the photocatalytic mechanism of  $Ga_2O_3/AC$  composites toward  $CH_4$  oxidation, ESR spectroscopy with spin trapping and labeling was chosen as an effective characterization technique. Here, we selected 5,5-dimethyl-1-pyrroline-N-oxide (DMPO)<sup>43</sup> as a spin-trapping agent for  $O_2^{\cdot-}$  radicals and 2,2,6,6-tetramethylpiperidine-1-oxyl (TEMPO)<sup>44</sup> as a spin-labeling agent for photogenerated electrons.

Photo-holes are considered as the predominant active species for photocatalytic oxidation of methane. It is demonstrated that the triplet ESR signal of TEMPO can diminish or even vanish if it is reduced by photogenerated electrons from semiconductors.<sup>44</sup> As a result, the generation of photo-electrons can be monitored accurately by observing the changes in the intensity of TEMPO signals. ESR spectrum of an aqueous TEMPO solution showed a stable signal having triplet peaks with intensity of 1 : 1 : 1 (Fig. 12A). The signal intensity decreased moderately after 3 min irradiation in the presence of bare  $Ga_2O_3$ ; however, a considerable decrease in the ESR signal was observed during the irradiation of 15%- $Ga_2O_3/AC$  suspension. It indicates that the introduction of AC can enhance the generation of photoelectrons greatly. Furthermore, the presence of photoelectrons is invariably accompanied by the generation of photoholes. Hence, the reduction of ESR signal intensity shown in Fig. 12A can reflect the formation of photoholes over  $Ga_2O_3/AC$  composites indirectly. In addition, as shown in Fig. 12B, the characteristic peaks of DMPO- $O_2^{\cdot-}$  can be observed in methanol suspensions of bare  $Ga_2O_3$  upon irradiation for 3 min.<sup>43</sup> For 15%- $Ga_2O_3/AC$  composites, the signal intensity of DMPO- $O_2^{\cdot-}$  increased obviously (about 3 times of bare  $Ga_2O_3$ ) under the same conditions. These results

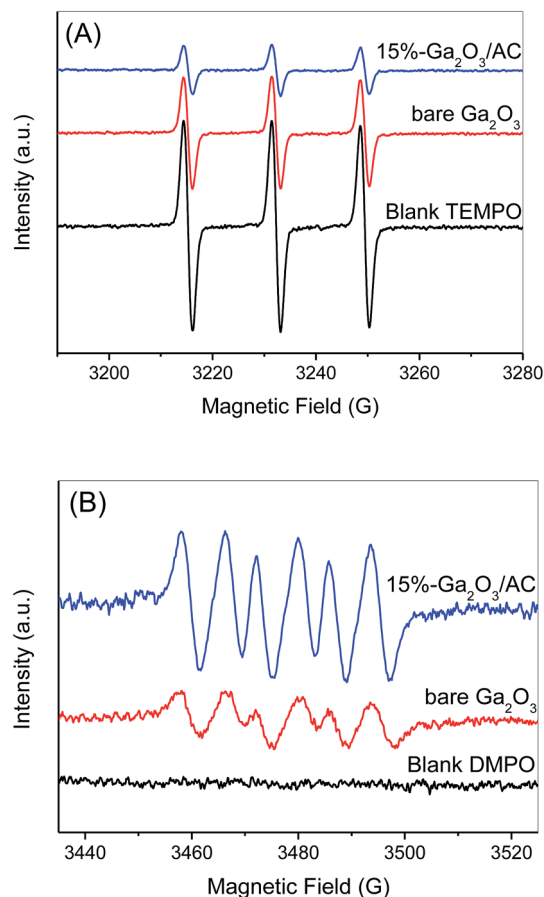


Fig. 12 ESR spectra obtained from bare  $Ga_2O_3$  and 15%- $Ga_2O_3/AC$  suspensions (A) 40 mM DMPO methanol solution and (B) 0.02 mM TEMPO aqueous solution. All spectra were recorded after 3 min of UV irradiation. The blank represented the solution containing spin probes alone under light illumination.

demonstrate that  $O_2^{\cdot-}$  can be generated over bare  $Ga_2O_3$  or  $Ga_2O_3/AC$  composites under UV irradiation and introduction of AC significantly enhanced the photogeneration of  $O_2^{\cdot-}$ .

The photocatalytic oxidation of  $CH_4$  over 15%- $Ga_2O_3/AC$  composites was further explored through a series of control experiments. As depicted in Fig. 13, the oxidation of  $CH_4$  was almost unchanged after adding TBA (a scavenger of  $\cdot OH$ <sup>45</sup>) into the reaction system, indicating that  $\cdot OH$  had little effect on photocatalytic oxidation of  $CH_4$  over  $Ga_2O_3/AC$  composites. When KI was added to the reaction system to trap the holes,<sup>46</sup> the  $CH_4$  oxidation was significantly inhibited, revealing that photogenerated holes were the major oxidative species for the photocatalytic  $CH_4$  oxidation. Addition of BQ (a scavenger of superoxide radicals<sup>47</sup>) clearly suppressed the  $CH_4$  oxidation, which suggests that  $O_2^{\cdot-}$  also play a critical role in the photocatalytic oxidation of  $CH_4$ . Adding  $K_2Cr_2O_7$  (an electron scavenger<sup>48</sup>) into the reaction system led to moderate decrease of photocatalytic oxidation for  $CH_4$ . All of the above experimental results were obtained in the presence of 79%  $N_2$  gas, 21%  $O_2$  gas and  $1.56 \text{ mmol L}^{-1} CH_4$ .

However, when adding electron scavenger  $K_2Cr_2O_7$  in the presence of 100%  $O_2$  gas and  $1.56 \text{ mmol L}^{-1} CH_4$ , the oxidation of  $CH_4$  exhibited slight increase. It might be ascribed to the fact





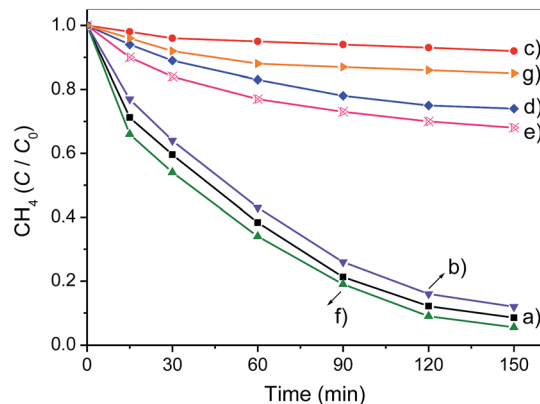


Fig. 13 Controlled experiments using different radical scavengers for the photocatalytic oxidation of CH<sub>4</sub> over 15%-Ga<sub>2</sub>O<sub>3</sub>/AC catalyst: (a) no scavenger, (b) TBA, (c) KI, (d) BQ, (e) K<sub>2</sub>Cr<sub>2</sub>O<sub>7</sub>, (f) K<sub>2</sub>Cr<sub>2</sub>O<sub>7</sub> + 100% O<sub>2</sub> gas, and (g) K<sub>2</sub>Cr<sub>2</sub>O<sub>7</sub> + 100% N<sub>2</sub> gas.

that trapping of photogenerated electrons with K<sub>2</sub>Cr<sub>2</sub>O<sub>7</sub> could benefit the generation of photoinduced holes. But the oxidation of CH<sub>4</sub> was significantly restrained in the presence of K<sub>2</sub>Cr<sub>2</sub>O<sub>7</sub>, 100% N<sub>2</sub> gas and 1.56 mmol L<sup>-1</sup> CH<sub>4</sub>. During the photocatalytic process of CH<sub>4</sub> oxidation, CH<sub>4</sub> was activated primarily *via* extracting hydrogen by photoinduced holes, consequently generating methyl radicals (<sup>•</sup>CH<sub>3</sub>). These experimental results imply that high concentration of O<sub>2</sub> can also react with <sup>•</sup>CH<sub>3</sub>, although there is no superoxide radicals.

As it is known, CH<sub>4</sub> is a highly flammable gas. CH<sub>4</sub> is unstable under high concentration of O<sub>2</sub> and can cause combustion and even explosive reactions. Hence, from the view of experimental safety, the photocatalytic experiments of CH<sub>4</sub> oxidation were performed in the presence of 79% N<sub>2</sub> gas and 21% O<sub>2</sub> gas unless otherwise stated. On the basis of the above experimental results, it is concluded that the reaction between <sup>•</sup>CH<sub>3</sub> and O<sub>2</sub><sup>•-</sup> is predominant for the photocatalytic oxidation of CH<sub>4</sub> in the presence of 79% N<sub>2</sub> gas and 21% O<sub>2</sub> gas.

The ESR results in Fig. 12 indicate that Ga<sub>2</sub>O<sub>3</sub>/AC composites facilitate the generation of photo-induced active species, such as O<sub>2</sub><sup>•-</sup> and photo-holes. Meanwhile, the weight ratios of Ga<sub>2</sub>O<sub>3</sub> have a decisive role in the photocatalytic activity of Ga<sub>2</sub>O<sub>3</sub>/AC composites (Fig. 7). Therefore, it was critical to investigate whether the weight ratios of Ga<sub>2</sub>O<sub>3</sub> had similar effects on the photoinduced generation of active species. The effects of Ga<sub>2</sub>O<sub>3</sub> weight ratios on the ESR signal intensity of DMPO-O<sub>2</sub><sup>•-</sup> and TEMPO were depicted in Fig. 14. A similar dependence on Ga<sub>2</sub>O<sub>3</sub> weight ratios was observed for O<sub>2</sub><sup>•-</sup> radicals and photoholes. An initial increase in the ESR signal intensity was noted for Ga<sub>2</sub>O<sub>3</sub>/AC composites with weight ratio of Ga<sub>2</sub>O<sub>3</sub> up to 15%. Diminishing ESR signal intensities were observed for composite samples having a higher weight ratio of Ga<sub>2</sub>O<sub>3</sub>. Importantly, it is of interest to note that the changes of ESR signals obtained for DMPO-O<sub>2</sub><sup>•-</sup> or TEMPO and the photocatalytic activity of CH<sub>4</sub> oxidation had a similar dependence on the weight ratios of Ga<sub>2</sub>O<sub>3</sub>. This correlation implied a mechanistic connection between the generation of photoholes or O<sub>2</sub><sup>•-</sup> radicals and the photocatalytic performance. The results also indicate

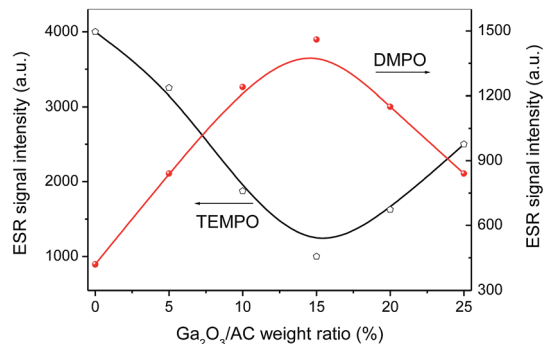
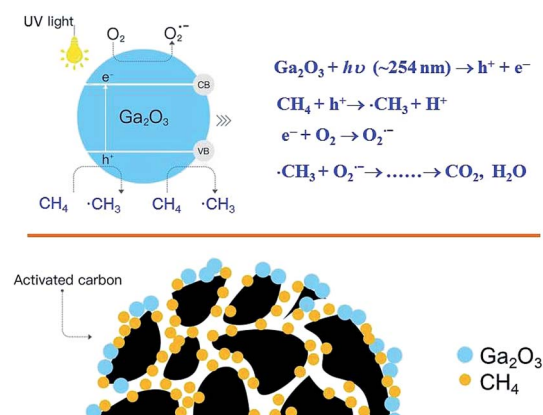


Fig. 14 Effect of Ga<sub>2</sub>O<sub>3</sub> weight ratios on the enhancement of photoinduced generation of superoxide radicals and photoelectrons.

photogenerated holes and O<sub>2</sub><sup>•-</sup> radicals play dominant roles in the photocatalytic oxidation of CH<sub>4</sub> over Ga<sub>2</sub>O<sub>3</sub>/AC composites, consistent with the results of active species trapping experiments.

For the photocatalytic oxidation of CH<sub>4</sub>, Ga<sub>2</sub>O<sub>3</sub>/AC catalysts are thought to act through a dynamic adsorption-photocatalysis process under UV irradiation. Ga<sub>2</sub>O<sub>3</sub>/AC composites exhibit higher performance for CH<sub>4</sub> oxidation compared with bare Ga<sub>2</sub>O<sub>3</sub>, which might be due to the following two aspects. One is the excellent adsorption capacity of AC for CH<sub>4</sub> molecules. The interface created between AC and Ga<sub>2</sub>O<sub>3</sub> phase facilitates the adsorption of CH<sub>4</sub> onto AC and the transfer of adsorbed CH<sub>4</sub> to catalytic active component Ga<sub>2</sub>O<sub>3</sub>. More importantly, AC support facilitates the dispersion of deposited Ga<sub>2</sub>O<sub>3</sub> nanoparticles (Fig. 2), inhibiting the agglomeration of catalytic active components. On the basis of above results, the proposed mechanism for photocatalytic oxidation of CH<sub>4</sub> upon Ga<sub>2</sub>O<sub>3</sub>/AC composites is depicted in Scheme 1. Under UV irradiation, photoinduced electrons and holes are generated upon the surface of Ga<sub>2</sub>O<sub>3</sub> nanoparticles. The initial step of CH<sub>4</sub> activation primarily involves the reaction with photogenerated holes. The photogenerated electrons can react with the adsorbed O<sub>2</sub> upon the surface of catalysts and generate O<sub>2</sub><sup>•-</sup> radicals. The obtained methyl radicals *via* abstracting the hydrogen of CH<sub>4</sub> are further oxidized by superoxide anion radicals. The



Scheme 1 Proposed mechanism for photocatalytic oxidation of CH<sub>4</sub> over Ga<sub>2</sub>O<sub>3</sub>/AC composites.



introduction of AC would enhance the surface adsorption of CH<sub>4</sub> molecules, the charge separation of photoinduced electron-hole pairs and the generation of active radical species, improving the photocatalytic properties toward CH<sub>4</sub> oxidation.

## 4. Conclusions

A high-performance Ga<sub>2</sub>O<sub>3</sub>/AC composite photocatalysts were successfully synthesized *via* a facile hydrolysis method combined with impregnation process. Photocatalytic oxidation of CH<sub>4</sub> was systematically investigated over bare Ga<sub>2</sub>O<sub>3</sub> and Ga<sub>2</sub>O<sub>3</sub>/AC composites in a fixed-bed tubular quartz reactor. The adsorption capacity and photocatalytic activity of Ga<sub>2</sub>O<sub>3</sub>/AC were greatly affected by the weight ratios of Ga<sub>2</sub>O<sub>3</sub> to AC. 15%-Ga<sub>2</sub>O<sub>3</sub>/AC composites exhibited the highest photocatalytic activity and 91.5% of CH<sub>4</sub> was decomposed after 150 min UV irradiation, which could be ascribed to strong adsorption ability and efficient separation of photo-generated electrons and holes. Besides, the photocatalytic oxidation of CH<sub>4</sub> obeys pseudo-first-order kinetics and the cycled experiment indicates that Ga<sub>2</sub>O<sub>3</sub>/AC composites possess stable photocatalytic performance for CH<sub>4</sub> oxidation. Moreover, the underlying photo-oxidation mechanism is also proposed on the basis of the results of ESR measurements and radicals scavenging experiments. The adsorbed CH<sub>4</sub> molecules upon the surface of Ga<sub>2</sub>O<sub>3</sub>/AC were activated primarily *via* the reaction with photo-generated holes and the as-obtained methyl radicals were further oxidized by superoxide anion radicals. The introduction of AC can enhance the surface adsorption of CH<sub>4</sub> molecules, the separation of photoinduced electron-hole pairs and the generation of active radical species, thus improving the photocatalytic performance of CH<sub>4</sub> oxidation. Hence, the photocatalytic technique with Ga<sub>2</sub>O<sub>3</sub>/AC composites could be considered as a promising method toward the removal of low concentration CH<sub>4</sub>.

## 5. Conflict of interest

There are no conflicts of interest to declare.

## Acknowledgements

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